# 2.7W Mono Filter-less Class-D Audio Amplifier

### **Features**

- Supply voltage range: 2.5 V to 5.5 V
- Support single-ended or differential analog input
- Low static operation current
- Low shut-down current
- Short power-on transient time
- Internal pull-low resistor on shut-down pins
- Short-circuit protection
- Over-temperature protection
- Loudspeaker power within 10% THD+N
  - 1.66W/ch into  $8\Omega$  loudspeaker
  - 2.70W/ch into  $4\Omega$  loudspeaker
- Loudspeaker efficiency
  - 90% @ 8Ω, THD+N=10%
  - 85% @ 4Ω, THD+N=10%
- MSOP-8, TDFN-9 and WLCSP-9 packages
- Integrated de-pop circuitry
- Internal generated 450kHz switching frequency

### **Applications**

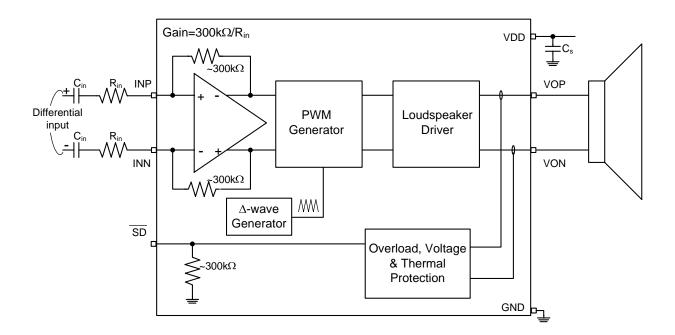
- Monitor audio
- PDA
- Portable multimedia devices
- Notebook computer
- Mobile phone

### **Description**

The EMA2011 is a mono, filter-less class-D audio amplifier. Operating with 5.0V loudspeaker driver supply, it can deliver 2.7W output power into 4  $\Omega$  loudspeaker within 10% THD+N or 2.2W at 1% THD+N.

The EMA2011 is a mono audio amplifier with high efficiency and suitable for the notebook computer, and portable multimedia device.

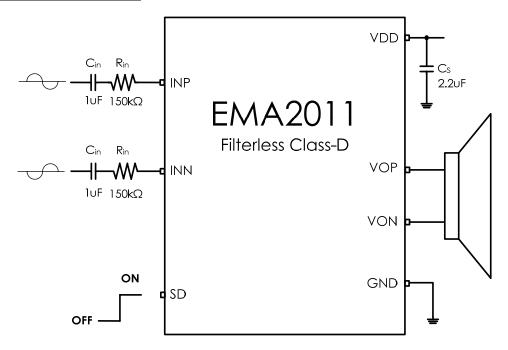
## **Functional Block Diagram**



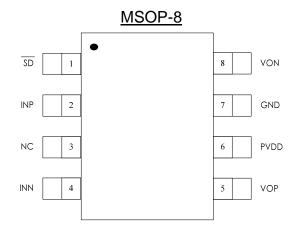
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# **Typical Application Circuit**



### **Pin Assignments**



### **Order information**

### EMA2011-50MA08GRR

50 5.0V Operation

MA08 MSOP-8 Package

GRR RoHS (Pb Free)

Rating: -40 to 85°C

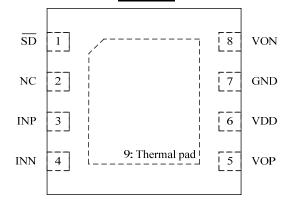
NRR RoHS & Halogen free (By Request)

Rating: -40 to 85°C

Package in Tape & Reel

Package in Tape & Reel

## TDFN-8



### **Order information**

### EMA2011-50FF08NRR

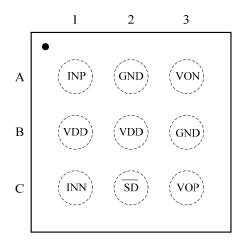
50 5.0V OperationFF08 TDFN-8 Package

NRR RoHS & Halogen free (By Request)

Rating: -40 to 85°C

Package in Tape & Reel

### WLCSP-9



### **Order information**

### EMA2011-50WL09GRR/NRR

50 5.0V Operation

WL09 WLCSP-9 Package

GRR RoHS (Pb Free)

Rating: -40 to 85°C

Package in Tape & Reel

NRR RoHS & Halogen free (By Request)

Rating: -40 to 85°C

Package in Tape & Reel



# Order, Mark and Packing Information

Package	Product ID	Marking	Packing
MSOP-8	EMA2011-50MA08GRR	EMP EMA2011 Tracking code  PIN1 DOT  1 2 3 4	3K units Tape & Reel
TDFN-8	EMA2011-50FF08NRR	EMP EMA2011 Tracking Code	5K units Tape & Reel
WLCSP-9	EMA2011-50WL09GRR	EMP Tracking Code	3K units Tape & Reel



# **Pin Description**

NAME		PIN		Ю	DESCRIPTION
INAIVIL	MSOP-8	TDFN-8	WLCSP-9	TYPE	DESCRIPTION
SD	1	1	C2	I	Shutdown EMA2011 (Low active logic)
INP	2	3	A1	I	Positive differential input
NC	3	2	N/A	NC	No internal connect
INN	4	4	C1	I	Negative differential input
VOP	5	5	A3	0	Positive output
VDD	6	6	B2	Р	Power supply
GND	7	7	A2, B3	G	Power ground
VON	8	8	C3	0	Negative output
Thermal pad	N/A	9	N/A	G	Must be connected the package thermal pad to PCB thermal land.

# **Available Package**

Package Type	Device no.	θ <sub>JA</sub> (°C/W)	Exposed Thermal Pad
MSOP-8		190	No
TDFN-8 (3x3mm)	EMA2011	45.8	Yes
WLCSP-9		128	No

# **Absolute Maximum Ratings**

SYMBOL	PARAMETER	MIN	MAX	UNIT
VDD	Supply for analog cells & loudspeaker driver	2.5	6.0	V
	Input voltage	-0.3	5.5	V
T <sub>stg</sub>	Storage temperature	-65	150	°C
T <sub>a</sub>	Ambient operating temperature	-40	85	°C

# **Recommended Operating Conditions**

SYMBOL	PARAMETER	MIN	MAX	UNIT
VDD	Supply for analog cells & loudspeaker driver	2.5	5.5	V
$V_{IH}$	High-Level Input Voltage	70% X VDD	VDD	V
V <sub>IL</sub>	Low-Level Input Voltage	0	35% X VDD	V



# **General Electrical Characteristics** (T<sub>A</sub>=25 °C)

SYMBOL	PARAMETER	CONDITION	MIN	TYP	MAX	UNIT
Iq	Operating current	VDD=SD=5V		5.7		mA
I <sub>PD</sub>	Supply current during power-down mode	VDD=5.0V; SD#=0		2	50	μΑ
V <sub>offset</sub>	Output offset voltage	Input ac grounded, VDD=2.5V ~ 5.0V		5	25	mV
Tsd	Junction temperature for driver shutdown		145	150	155	°C
Thys	Temperature hysteresis for recovery from shutdown		115	120	125	°C
f <sub>sw</sub>	Switching rate of loudspeakers driver		300	450	600	kHz
Ton	Turn-on time	VDD = 3.6 V		1	4	msec
R <sub>SC</sub>	Loudspeaker short-circuit detect resistance	VDD = 5.0 V		2.8	3.2	ohm

# **Electrical Characteristics and Specifications for Loudspeaker**

Gain= 2 V/V, Load=8Ω, f<sub>in</sub>=1 kHz (unless otherwise noted)

SYMBOL	PARAMETER	CONE	DITION	MIN	TYP	MAX	UNIT
		VDD=5.0V			1.66		W
		VDD=5.0V	THD+N = 1 %		1.35		W
Po	PMS Output Power	VDD=3.6V	THD+N = 10 %		0.85		W
Γ0	RMS Output Power	VDD=3.6V	THD+N = 1 %		0.68		W
		VDD=2.5V	THD+N = 10 %		0.39		W
		VDD=2.5V	THD+N = 1 %		0.31		W
	Total Harmonia Distortion plus	VDD=5.0V, Po=1.0W			0.24		%
THD+N	Total Harmonic Distortion plus  Noise	VDD=3.6V, Po=0.5W			0.34		%
	Noise	VDD=2.5V, Po=0.2W			0.4		%
SNR	Signal to Noise Ratio	VDD=5.0V, Po=1	VDD=5.0V, Po=1.0W		94		dB
		VDD=3.6V, V <sub>ripple</sub>	=200mVpp				
PSRR	Power Supply Rejection Ratio	Inputs ac grounded with Ci=2μF			-60		dB
		f=217 Hz					
CMRR	Common-Mode Rejection Ratio	VDD=3.6V, V <sub>IC</sub> =1Vpp, f=217Hz			-50		dB
$V_n$	Output integrated noise	VDD=3.6V			80		\/
	(A-weighted)	f <sub>in</sub> =20Hz ~ 20kHz	Z		50		μV
η	Efficiency	VDD=5V, THD+N	N=10%		88.5		%



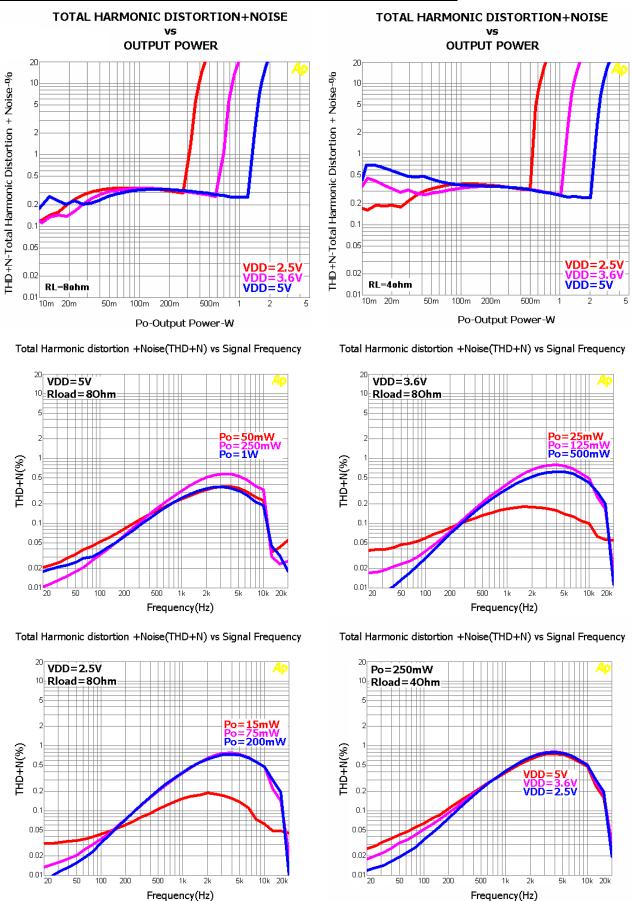
## • Gain= 2 V/V, Load= $4\Omega$ , $f_{in}$ =1 kHz (unless otherwise noted)

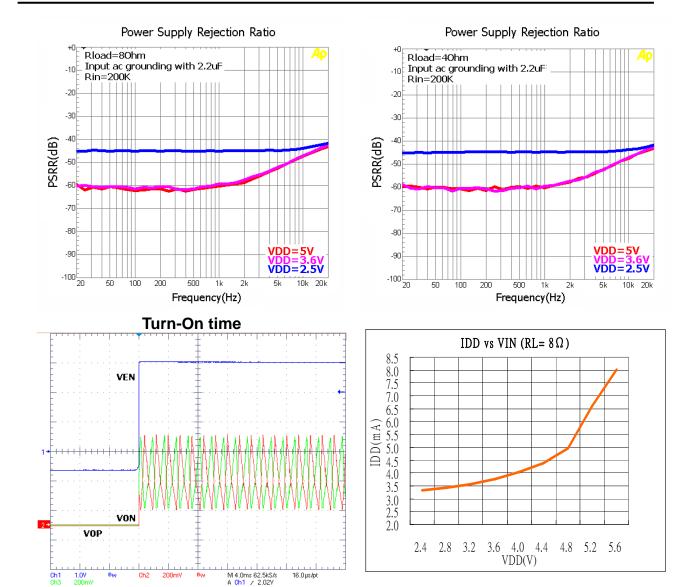
SYMBOL	PARAMETER	CONE	DITION	MIN	TYP	MAX	UNIT
		VDD=5.0V	THD+N = 10 %		2.7		W
		VDD=3.0V	THD+N = 1 %		2.2		W
В	PMS Output Power	VDD=3.6V	THD+N = 10 %		1.3		W
Po	RMS Output Power	VDD=3.6V	THD+N = 1 %		1.1		W
		\/DD 2.5\/	THD+N = 10 %		0.6		W
		VDD=2.5V	THD+N = 1 %		0.5		W
	Total Harmonia Dietortion plus	VDD=5.0V, Po=2.0W			0.24		%
THD+N	Total Harmonic Distortion plus  Noise	VDD=3.6V, Po=1.0W			0.34		%
	Noise	VDD=2.5V, Po=0.5W			0.4		%
SNR	Signal to Noise Ratio	VDD=5.0V, Po=1.8W			94		dB
		VDD=3.6V, V <sub>ripple</sub> =200mVpp					
PSRR	Power Supply Rejection Ratio	Inputs ac ground		-60		dB	
			f=217 Hz				
CMRR	Common-Mode Rejection Ratio	VDD=3.6V, V <sub>IC</sub> =1Vpp, f=217Hz			-55		dB
V <sub>n</sub>	Output integrated noise	VDD=3.6V			02		
	(A-weighted)	$f_{in}$ =20Hz ~ 20kHz		83			μV
η	Efficiency	VDD=5.0V, THD	+N=10%		80		%

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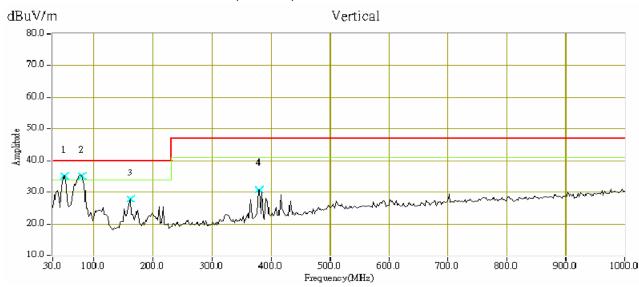


## Typical Characteristics (Gain= 2 V/V, unless otherwise noted)

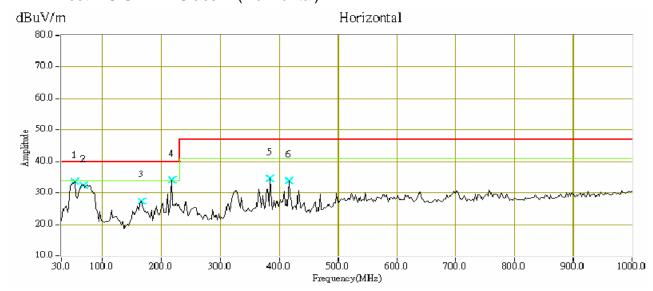




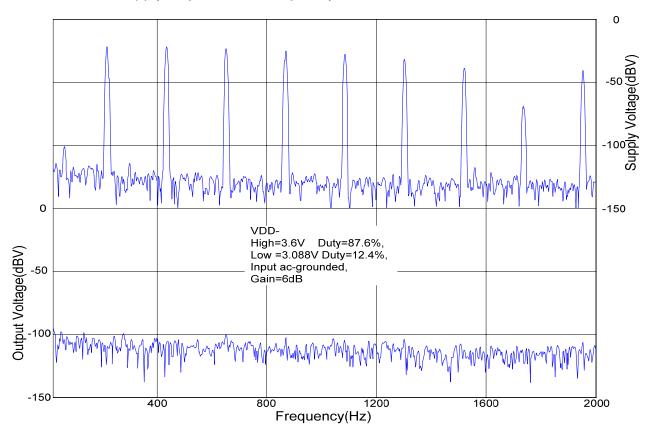
## ■ EMI Test – CISPR22 Class B (Vertical)



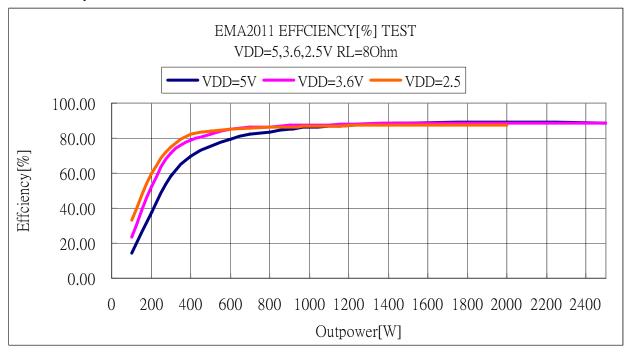
## • EMI Test - CISPR22 Class B (Horizontal)

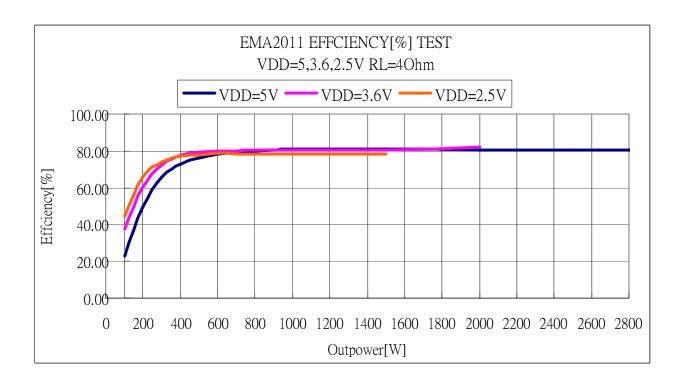


# • GSM Power Supply Rejection vs Frequency



## Efficiency







## **Operation Descriptions**

- Self-protection circuits (Typical values are used below.)
   EMA2011 has built-in over-temperature, overload and under-voltage detectors.
  - (i) If the internal junction temperature is higher than 150°C, the outputs of loudspeaker drivers will be disabled and connected to ground and the temperature hysteresis for EMA2011 to return to normal operation is about 30°C. The variation of protected temperature is around 10%.
  - (ii) To protect loudspeaker drivers from current damage when the wires connected to loudspeakers are shorted to one another or shorted to GND, circuits for the detection of output loading are built in the EMA2011. For normal operation, loudspeaker resistance is larger than 3.2Ω is required. Otherwise, overload detectors may activate. Once overload detector is active, loudspeaker drivers will be disabled and at low state. EMA2011 will be recovery from overload fault by pulling SD# down to low and back to high after removing the short. Once the lines connected to loudspeakers are shorted to VDD, EMA2011 will be burnt.
  - (iii) When the VDD voltage is lower than 2.1V, EMA2011 will disable and loudspeaker drivers are at low state, cease EMA2011 beside voltage detector circuit. When VDD becomes larger than 2.2V, EMA2011 will return to normal operation.
- Anti-pop design

EMA2011 is with anti-pop design. Annoying pop sounds during initial power on and power down/up are suppressed. When one of the operations mentioned above is applied, EMA2011 will internally generate appropriate control signals to suppress pop sounds.

### **Application Circuit Information**

Input resistors (R<sub>in</sub>) and input capacitors (C<sub>in</sub>)

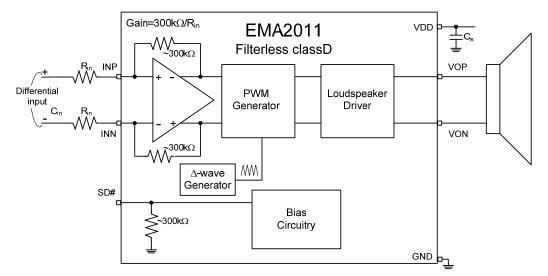
The total gain of the audio amplifier (EMA2011) is set by input resistor ( $R_{in}$ ) according to the following equation (a). The performance at low frequency (bass) is affected by the corner frequency ( $f_c$ ) of the high-pass filter composed of input resistors ( $R_{in}$ ) and input capacitors ( $C_{in}$ ), determined in equation (b).

$$Gain = \frac{300k\Omega}{R_{in}} \left( V_{V} \right) \cdot \cdot \cdot \cdot \cdot \cdot (a)$$

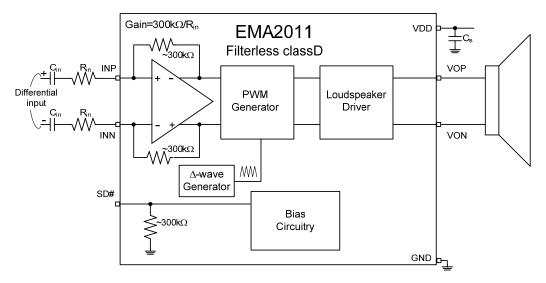
$$f_c = \frac{1}{2\pi R_{in} C_{in}} (Hz) \cdots (b)$$

For differential audio signal application, the input capacitors ( $C_{in}$ ), for DC decoupling, are not required. When single-ended audio source is used, the input capacitors ( $C_{in}$ ) are required.

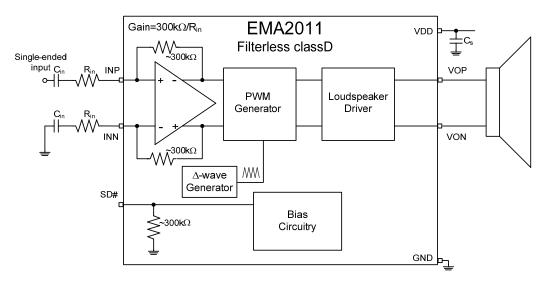
• Cost effective application circuit for fully differential input



Suggested application circuit for fully differential input

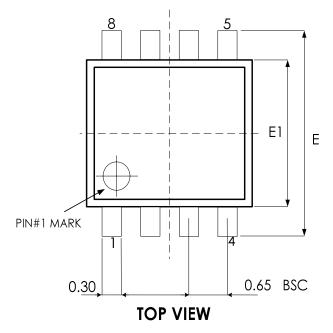


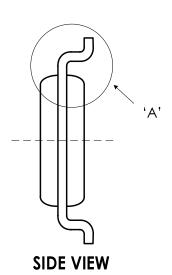
Suggested application circuit for single-ended input

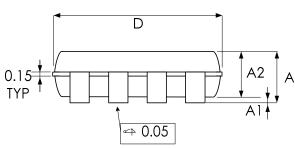


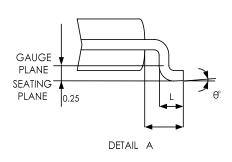
# **Package Dimensions**

# • MSOP - 8L









**BOTTOM VIEW** 

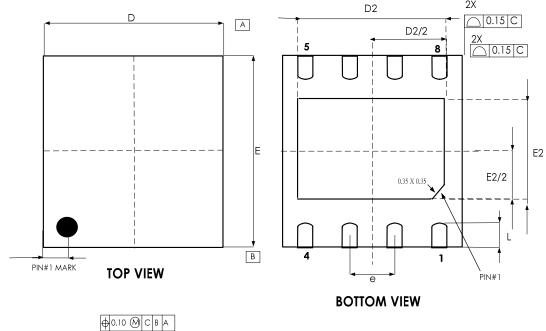
SYMBPLS	MIN.	NOM.	MAX.
Α	l		1.1
A1	0		0.15
A2	0.75	0.85	0.95
D	3.00 BSC		
Е		4.90 BSC	
E1		3.00 BSC	
L	0.4	0.6	0.8
L1	0.95 BSC		
θ°	0	_	8

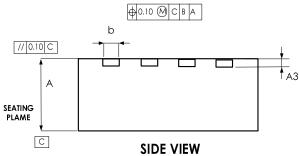
UNIT: mm



# **Package Dimensions**

# • TDFN - 8L (3x3x.75 mm)



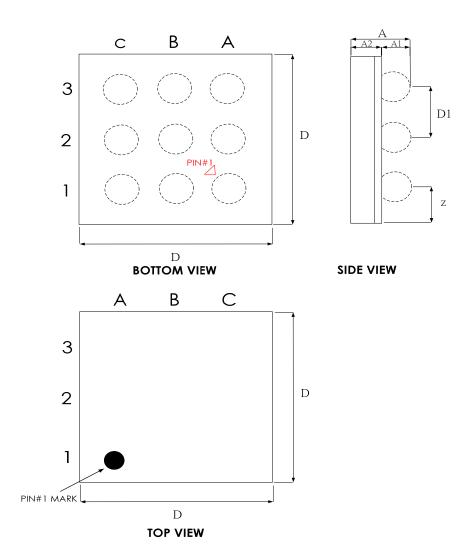


		COMMON					
SYMBOL	DIMEN:	SIONS MII	LIMETER	DIM	ENSIONS	INCH	
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
Α	0.70	0.75	0.80	0.027	0.029	0.031	
А3	0.203 BSC			0.008 BSC			
b	0.25	0.30	0.35	0.009	0.011	0.013	
D	2.85	3.00	3.15	0.111	0.117	0.122	
D2	2.20	2.30	2.40	0.085	0.089	0.093	
Е	2.85	3.00	3.15	0.111	0.117	0.122	
E2	1.50	1.60	1.70	0.058	0.062	0.066	
е	0.650 BSC				0.024 BSC	С	
L	0.30	0.35	0.40	0.011	0.013	0.015	



# **Package Dimensions**

• WCSP - 9L (1.45x1.45 mm)



Symbol	Dimensions in millimeter				
	min.	typ.	max.		
Α	0.585	0.650	0.715		
A1	0.210	0.235	0.260		
A2	0.355	0.380	0.405		
D	1.420	1.420 1.460 1.500			
D1	0.50				
Z		0.23			



# **Revision History**

Revision	Date	Description
2.0	2009.05.08	EMP transferred from version 1.3
2.1	2010.07.29	To correct the pins of VOP & VON descried mistake for all page.

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